Ordering number:ENN2094B

PNP/NPN Epitaxial Planar Silicon Transistors

2SB1135/2SD1668

50V/7A Switching Applications

Applications

· Relay drivers, high-speed inverters, converters, and other general high-current switching applications.

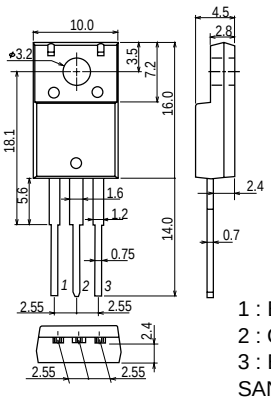
Features

· Low-saturation collector-to-emitter voltage : $V_{CE(sat)}$=–0.4V max.
· Wide ASO leading to high resistance to breakdown.
· Micaless package facilitating mounting.

Package Dimensions

unit:mm

2041A



1 : Base
2 : Collector
3 : Emitter
SANYO : TO-220ML

( ) : 2SB1135

Specifications

Absolute Maximum Ratings at Ta = 25˚C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V_{CBO}		(–)60	V
Collector-to-Emitter Voltage	V_{CEO}		(–)50	V
Emitter-to-Base Voltage	V_{EBO}		(–)6	V
Collector Current	I_C		(–)7	A
Collector Current (Pulse)	I_{CP}		(–)12	A
Collector Dissipation	P_C		2	W
		Tc=25˚C	30	W
Junction Temperature	Tj		150	˚C
Storage Temperature	Tstg		–55 to +150	˚C

Electrical Characteristics at Ta = 25˚C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I_{CBO}	V_{CB}=(–)40V, I_E=0			(–)0.1	mA
Emitter Cutoff Current	I_{EBO}	V_{EB}=(–)4V, I_C=0			(–)0.1	mA
DC Current Gain	$h_{FE}1$	V_{CE}=(–)2V, I_C=(–)1A	70*		280*	
	$h_{FE}2$	V_{CE}=(–)2V, I_C=(–)5A	30			
Gain-Bandwidth Product	f_T	V_{CE}=(–)5V, I_C=(–)1A		10		MHz

* : The 2SB1135/2SD1668 are classified by 1A h_{FE} as follows :

Continued on next page.

Rank	Q	R	S
h_{FE}	70 to 140	100 to 200	140 to 280

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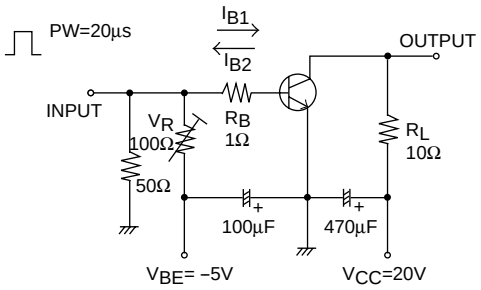
SANYO Electric Co.,Ltd. Semiconductor Company
TOKYO OFFICE Tokyo Bldg., 1-10, 1 Chome, Ueno, Taito-ku, TOKYO, 110-8534 JAPAN

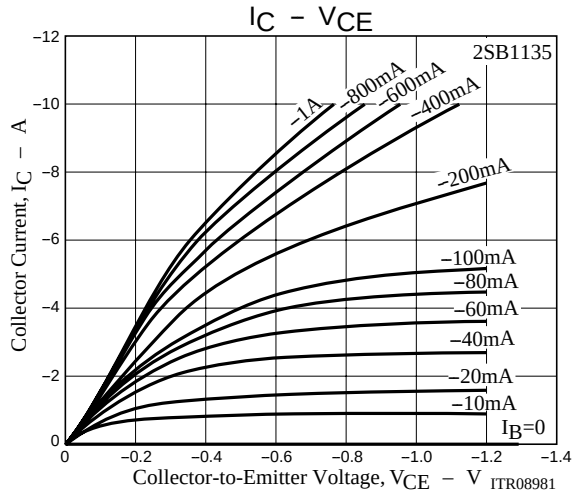
Continued from preceding page.

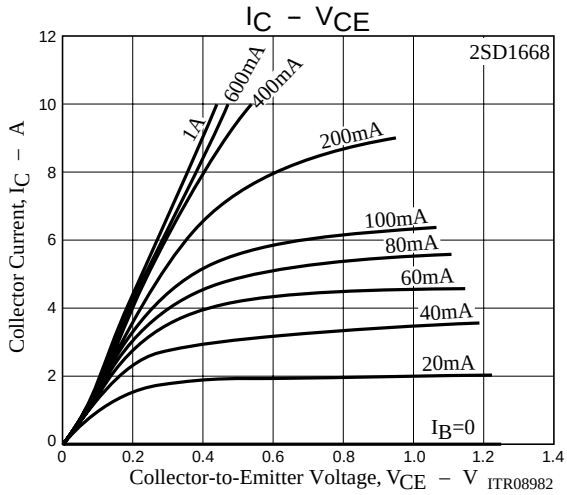
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)}$	I_C=(–)4A, I_B=(–)0.4A			(–)0.4	V
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	I_C=(–)1mA, I_E=0	(–)60			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	I_C=(–)1mA, R_{BE}=∞	(–)50			V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	I_E=(–)1mA, I_C=0	(–)6			V
Rise Time	t_{on}	See specified Test Circuti.		0.2		µs
Storage Time	t_{stg}	See specified Test Circuit.		(0.7)		µs
				0.9		µs
Fall Time	t_f	See specified Test Circuit.		(0.1)		µs
				0.3		µs

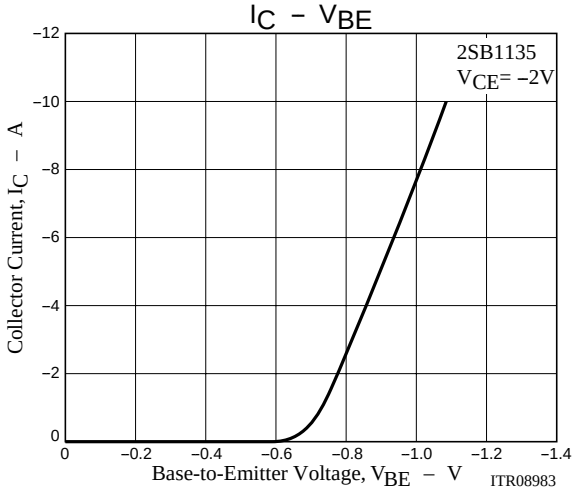
Switching Time Test Circuit

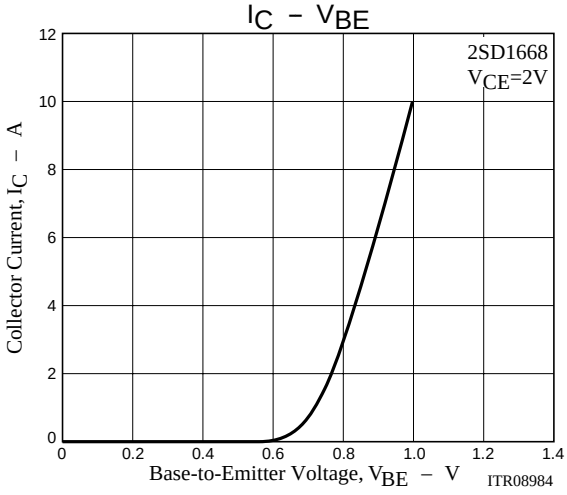


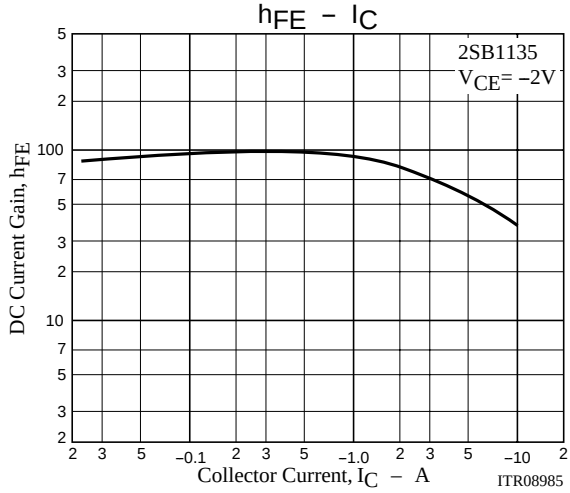
I_C=10I_{B1}= −10I_{B2}=2A
(For PNP, the polarity is reversed.)

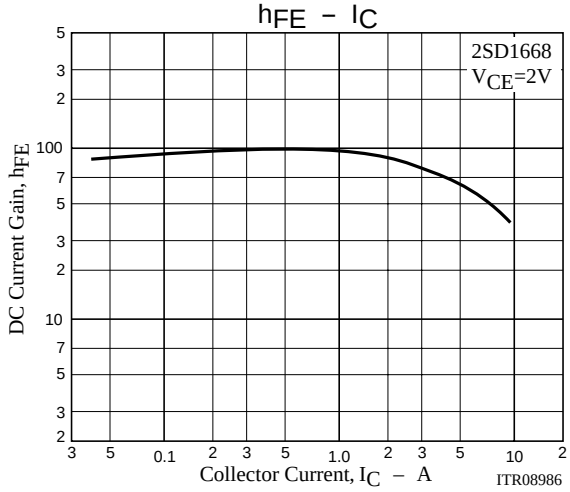


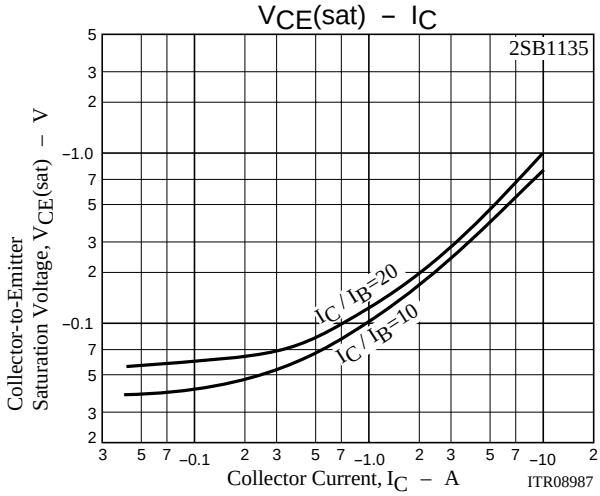


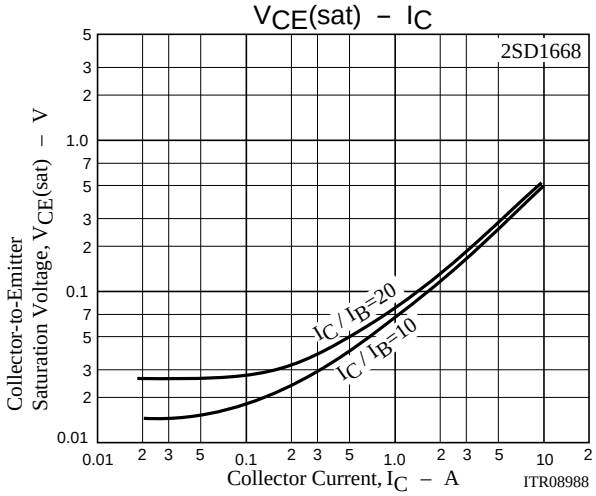


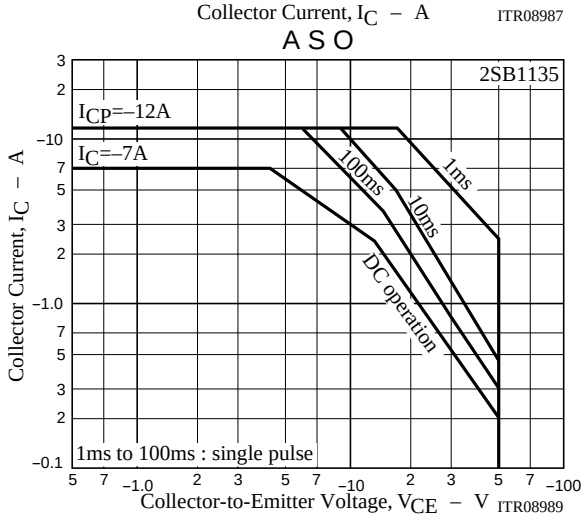


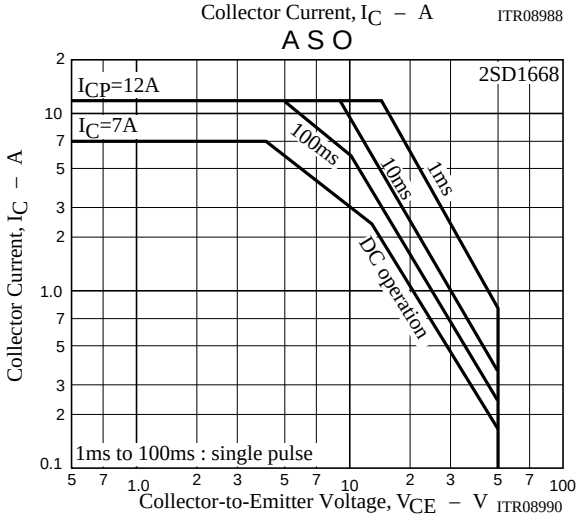

hFE – IC
2SB1135
VCE= –2V
DC Current Gain, hFE
Collector Current, IC – A
ITR08985

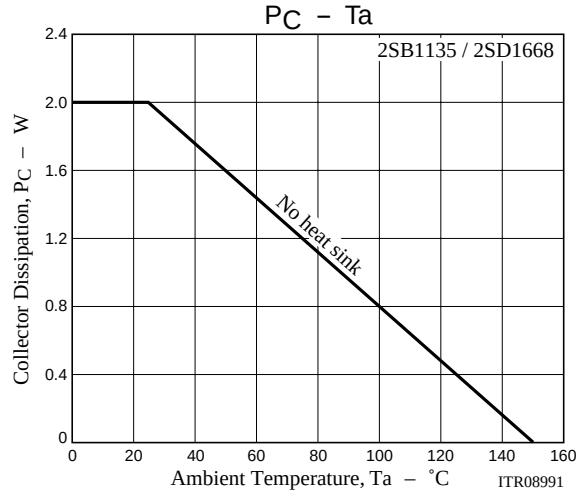

hFE – IC
2SD1668
VCE=2V
DC Current Gain, hFE
Collector Current, IC – A
ITR08986

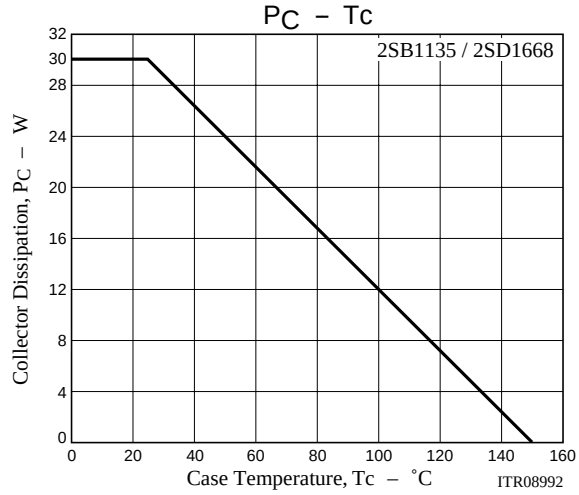

VCE(sat) – IC
2SB1135
IC / IB=20
IC / IB=10
Collector-to-Emitter Saturation Voltage, VCE(sat) – V
Collector Current, IC – A
ITR08987


VCE(sat) – IC
2SD1668
IC / IB=20
IC / IB=10
Collector-to-Emitter Saturation Voltage, VCE(sat) – V
Collector Current, IC – A
ITR08988


A S O
2SB1135
ICP=–12A
IC=–7A
1ms
10ms
100ms
DC operation
1ms to 100ms : single pulse
Collector Current, IC – A
Collector-to-Emitter Voltage, VCE – V
ITR08989


A S O
2SD1668
ICP=12A
IC=7A
1ms
10ms
100ms
DC operation
1ms to 100ms : single pulse
Collector Current, IC – A
Collector-to-Emitter Voltage, VCE – V
ITR08990


PC – Ta
2SB1135 / 2SD1668
No heat sink
Collector Dissipation, PC – W
Ambient Temperature, Ta – ˚C
ITR08991


PC – Tc
2SB1135 / 2SD1668
Collector Dissipation, PC – W
Case Temperature, Tc – ˚C
ITR08992

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